

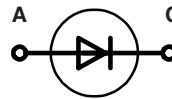
Fast Recovery Epitaxial Diode (FRED)

$$V_{RRM} = 600 \text{ V}$$

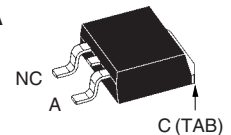
$$I_{FAVM} = 20 \text{ A}$$

$$t_{rr} = 35 \text{ ns}$$

V_{RSM} V	V_{RRM} V	Type
600	600	DSEI 19-06AS



TO-263 AA



A = Anode, C = Cathode,
NC = No connection, TAB = Cathode

Symbol	Conditions	Maximum Ratings
I_{FRMS}	$T_{VJ} = T_{VJM}$	25 A
I_{FAVM} ①	$T_C = 65^\circ\text{C}$; rectangular, $d = 0.5$	20 A
I_{FRM}	$t_p < 10 \mu\text{s}$; rep. rating, pulse width limited by T_{VJM}	150 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	100 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	110 A
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	85 A
	$t = 8.3 \text{ ms}$ (60 Hz), sine	95 A
I^2t	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	50 A ² s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	50 A ² s
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine	36 A ² s
	$t = 8.3 \text{ ms}$ (60 Hz), sine	37 A ² s
T_{VJ}		-40...+150 °C
T_{VJM}		150 °C
T_{stg}		-40...+150 °C
P_{tot}	$T_C = 25^\circ\text{C}$	61 W
Weight		2 g

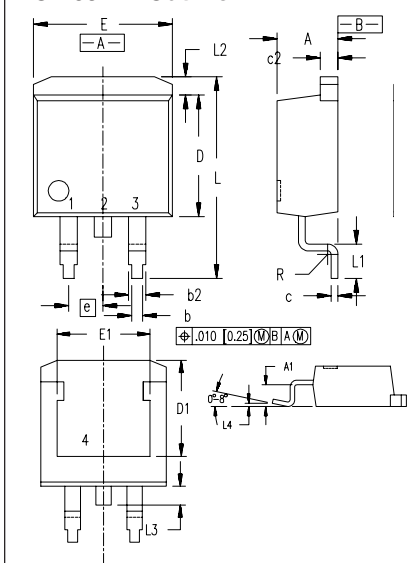
Symbol	Conditions	Characteristic Values
		typ. max.
I_R	$T_{VJ} = 25^\circ\text{C}$; $V_R = V_{RRM}$	50 μA
	$T_{VJ} = 25^\circ\text{C}$; $V_R = 0.8 \cdot V_{RRM}$	25 μA
	$T_{VJ} = 125^\circ\text{C}$; $V_R = 0.8 \cdot V_{RRM}$	3 mA
V_F	$I_F = 16 \text{ A}$; $T_{VJ} = 150^\circ\text{C}$	1.5 V
	$T_{VJ} = 25^\circ\text{C}$	1.7 V
V_{T0}	For power-loss calculations only	1.12 V
r_T	$T_{VJ} = T_{VJM}$	23.2 m Ω
R_{thJC}		2 K/W
t_{rr}	$I_F = 1 \text{ A}$; $-di/dt = 50 \text{ A}/\mu\text{s}$; $V_R = 30 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$	35 50 ns
I_{RM}	$V_R = 350 \text{ V}$; $I_F = 12 \text{ A}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$ $L \leq 0.05 \mu\text{H}$; $T_{VJ} = 100^\circ\text{C}$	4 4.4 A

① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle $d = 0.5$
Data according to IEC 60747

Features

- International standard surface mount package JEDEC TO-263 AA
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM} -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

TO-263 AA Outline



Dim.	Millimeter	Inches
	Min. Max.	Min. Max.
A	4.06 4.83	.160 .190
A1	2.03 2.79	.080 .110
b	0.51 0.99	.020 .039
b2	1.14 1.40	.045 .055
c	0.46 0.74	.018 .029
c2	1.14 1.40	.045 .055
D	8.64 9.65	.340 .380
D1	7.11 8.13	.280 .320
E	9.65 10.29	.380 .405
E1	6.86 8.13	.270 .320
e	2.54 BSC	.100 BSC
L	14.61 15.88	.575 .625
L1	2.29 2.79	.090 .110
L2	1.02 1.40	.040 .055
L3	1.27 1.78	.050 .070
L4	0 0.38	0 .015
R	0.46 0.74	.018 .029

IXYS reserves the right to change limits, test conditions and dimensions

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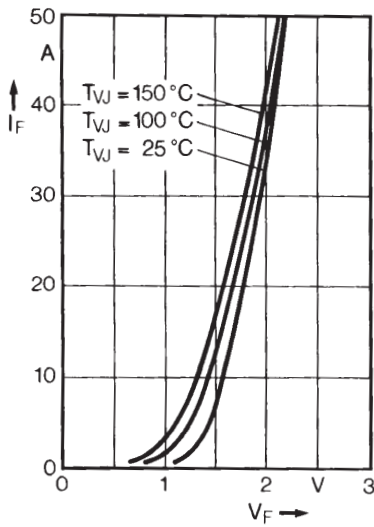


Fig. 1 Forward current versus voltage drop.

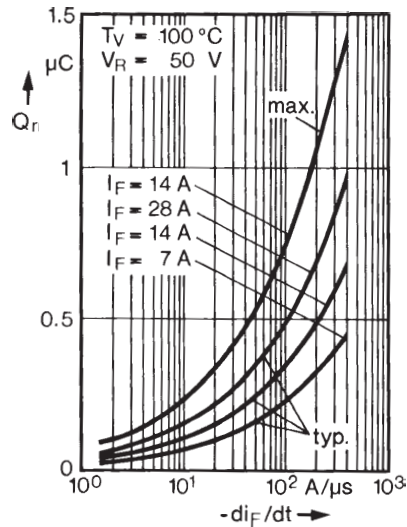


Fig. 2 Recovery charge versus $-di_F/dt$.

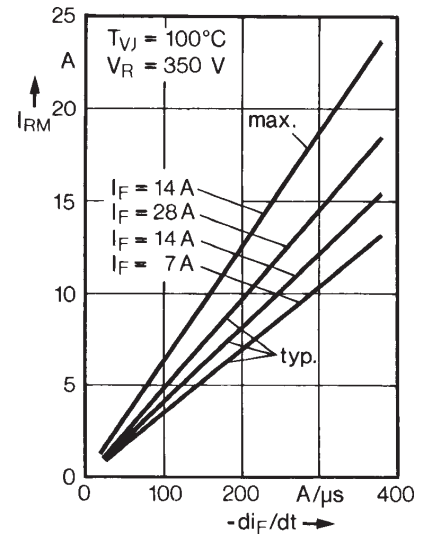


Fig. 3 Peak reverse current versus $-di_F/dt$.

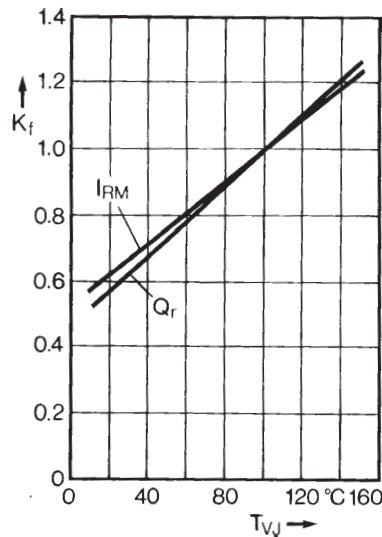


Fig. 4 Dynamic parameters versus junction temperature.

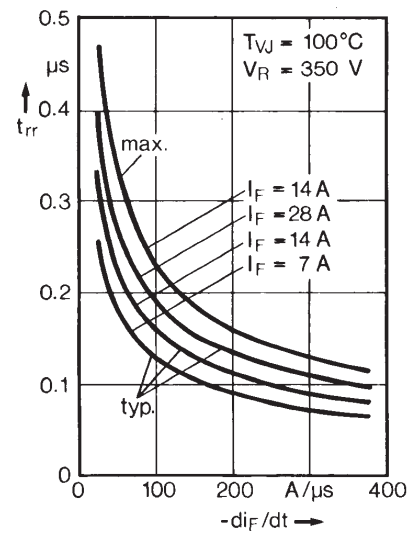


Fig. 5 Recovery time versus $-di_F/dt$.

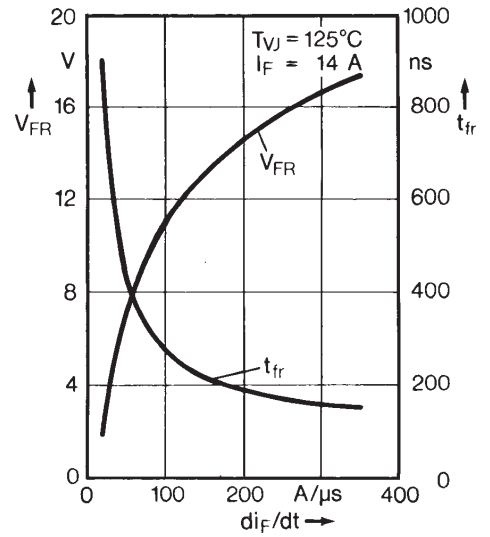


Fig. 6 Peak forward voltage versus di_F/dt .

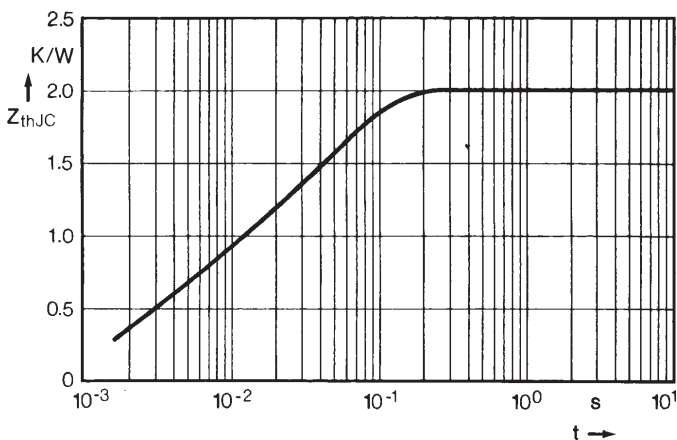


Fig. 7 Transient thermal impedance junction to case.